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FIELD STRENGTH TEST REPORT

Report Number: M160836

Test Sample: Cellsafe Chip

Host Model number: Apple iPhone 5,

Apple iPhone 6, Apple iPhone 6 Plus, Samsung Galaxy S5, Samsung Galaxy S6

Tested For: Panasales Clearance Centre Pty Ltd

(trading as Cellsafe)

Date of Issue: 02 September 2016

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Tested for: Panasales Clearance Centre Pty Ltd (trading as Cellsafe)

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Test Requirements: Field strength measurements performed on Apple iPhone 5 / 6 / 6 Plus and

Samsung Galaxy S5 / S6, with and without Cellsafe Chip

Test Dates: 25th & 29th August 2016

Test Engineer: Larry Phuah

Authorised Signatory: Andrew Whiteford

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Electric Field Strength Test Report

EMC Technologies Report M160427

1.0 INTRODUCTION

Electric Field Strength Measurements (Peak and Polar) were made from an Apple iPhone 5, an Apple iPhone 6, an Apple iPhone 6 Plus, a Samsung Galaxy S5 and a Samsung Galaxy S6 with and without the Cellsafe Chip fitted. The results were compared to determine if there was a reduction in the transmitted electric field strength when the mobile phones were fitted with the Cellsafe Chip.

The Cellsafe Chips (test samples) and mobile phones were provided by the client. The results herein apply only to the test samples.

2.0 TEST SAMPLE DESCRIPTION and TEST SETUP DETAILS

(Information supplied by the Client)

Test Sample: Cellsafe Chip

Host Model Number: 1. Apple iPhone 5 (Serial No. : C38JGND8F39D

2. Apple iPhone 6 (Serial No.: C36ND084G5MP

3. Apple iPhone 6 Plus (Serial No.: C39PX0FKFG5R0

4. Samsung Galaxy S5

(Serial No.: LMY47X.G9201_5.1.1_0039)

5. Samsung Galaxy S6

(Serial No.: KOTH9H.G9001DVUIANC6)

2.1 Product Description

(Information supplied by the Client)

The Cellsafe Chip contains a micro-thin printed circuit board designed to channel radiation away from the user's head and body without adversely affecting the signal field strength (connectivity).

2.2 Operating Conditions

The mobile phones (Equipment Under Test) were operated using an Anritsu MT8820A Radio Communication Analyzer to simulate a call made by the EUT. The channel bands utilised in the measurements are shown in the table below. The power level was set to maximum.

| Band (MHz) | Uplink Frequency | Channel | Nominal Power (dBm) |
|---------------|------------------|---------|---------------------|
| 850 | 836.6 MHz | 4183 | 26 |
| 1900 | 1880 MHz | 9400 | 26 |

2.3 Test Setup

Measurements were made inside a compliant CISPR 16-1-4 semi-anechoic chamber meeting the requirements for a test volume of $2m \times 2m \times 2m$ at 3 and 10 metre distances over the frequency range 30 MHz to 6000 MHz.

The EUT was placed vertically upright with the bottom of the phone facing upwards supported with a foam holder at a height of 1.5 m above the ground plane in the centre of the turn table with the front face of the EUT facing the 0 angle of the turn table. The iPhone 5 was placed at 0.8 m above the ground plane. The antenna height was fixed at 1.6 m. The turntable was rotated through 360 to measure field strength pattern in the Horizontal plane.

The placement of the Cellsafe chip on the EUT was performed by the client.

3.0. RESULTS

The results of the tests are contained on polar plot graphs 1 to 5 in Appendix B. In each graph, the difference between the two traces is the difference in the electric field strength measured from the EUT while it was in transmitting.

3.1 Peak Field Strength Measurement Results

| Uplink Frequency | Model | Radiated Electric Field Strength Measurement (Max Emission) | | Overall Average* |
|---------------------|------------------------|---|-------------|--------------------------|
| (MHz) | | No Chip | With Chip | Change of Field Strength |
| | Apple iPhone 5 | 93.6 dBμV/m | 93.2 dBμV/m | -0.78 dB |
| 836.6 | Apple iPhone 6 | 95.6 dBμV/m | 95.6 dBμV/m | -0.78 dB |
| 030.0 | Apple iPhone 6 Plus | 96.9 dBμV/m | 95.7 dBμV/m | -0.93 dB |
| | Samsung Galaxy S5 | 95.5 dBμV/m | 96.4 dBμV/m | +0.87 dB |
| 1880 | Samsung Galaxy S6 | 60.6 dBμV/m | 59.3 dBμV/m | -1.28 dB |

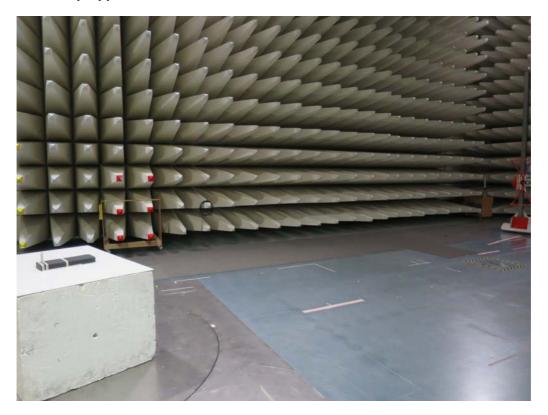
^{*}The average was calculated from the measured field strength (linear 1 degree values) in increments from 0 to 360 degrees.

4.0 CONCLUSION

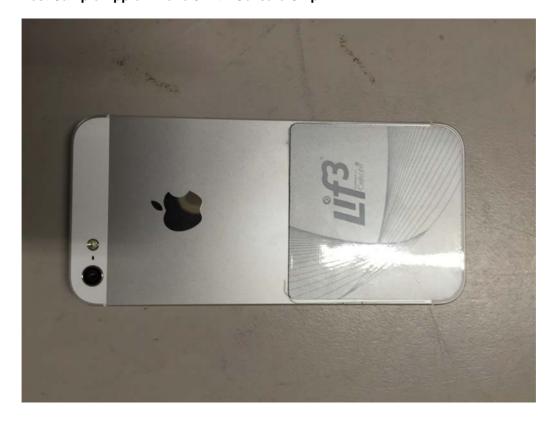
The Cellsafe Chip, tested on behalf of Panasales Clearance Centre Pty Ltd (trading as Cellsafe), was found to have a minimal impact on the average signal field strength of the Apple iPhone 5, Apple iPhone 6, Apple iPhone 6 Plus, Samsung Galaxy S5 and the Samsung Galaxy S6 at the tested Uplink Frequencies.

APPENDIX A1 TEST SETUP & SAMPLE PHOTOGRAPHS

Test Setup Apple iPhone 5

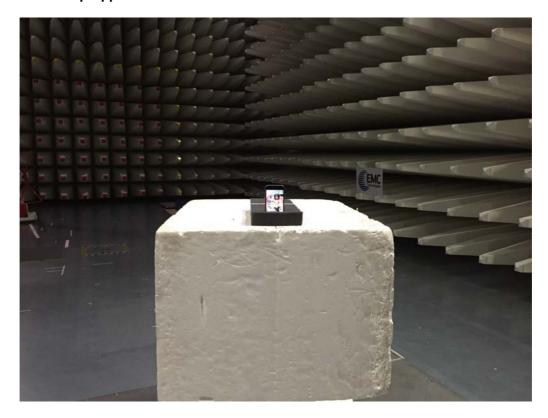


Test Sample Apple iPhone 5 with Cellsafe Chip



APPENDIX A2 TEST SETUP & SAMPLE PHOTOGRAPHS

Test Setup Apple iPhone 6

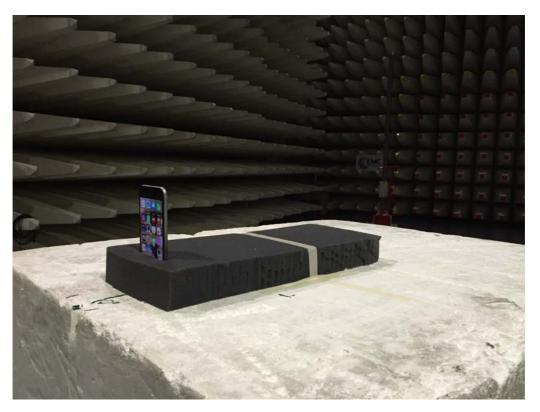


Test Sample Apple iPhone 6 with Cellsafe Chip



APPENDIX A3 TEST SETUP & SAMPLE PHOTOGRAPHS

Test Setup Apple iPhone 6 Plus

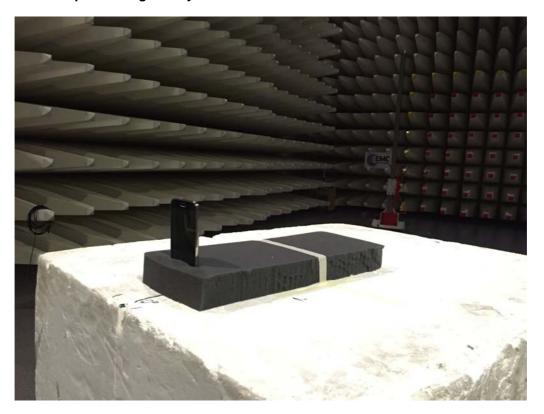


Test Sample Apple iPhone 6 Plus with Cellsafe Chip



APPENDIX A4 TEST SETUP & SAMPLE PHOTOGRAPHS

Test Setup Samsung Galaxy S5

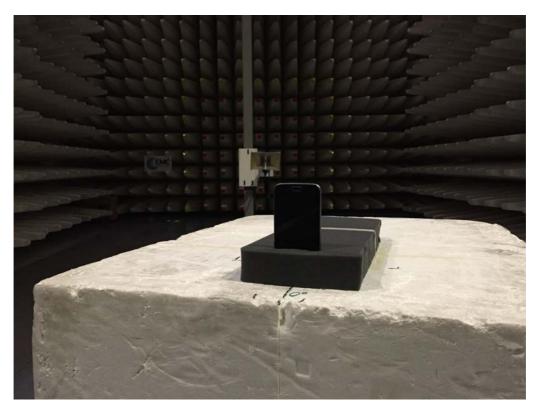


Test Sample Samsung Galaxy S5 with Cellsafe Chip



APPENDIX A5 TEST SETUP & SAMPLE PHOTOGRAPHS

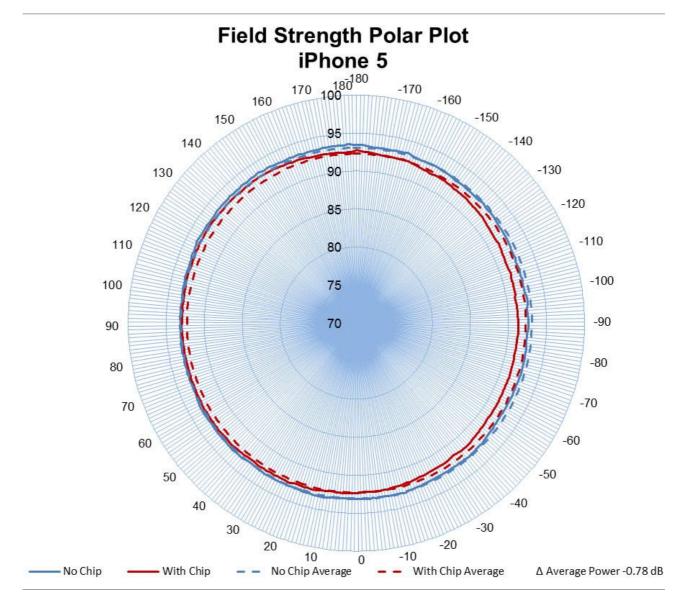
Test Setup Samsung Galaxy S6



Test Sample Samsung Galaxy S6 with Cellsafe Chip



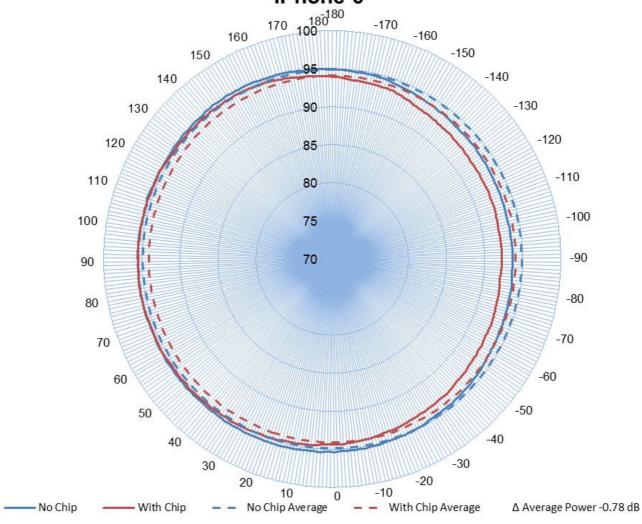
APPENDIX B1 POLAR RADIATION PATTERN MEASUREMENT



Graph 1 - Apple iPhone 5

APPENDIX B2 POLAR RADIATION PATTERN MEASUREMENT

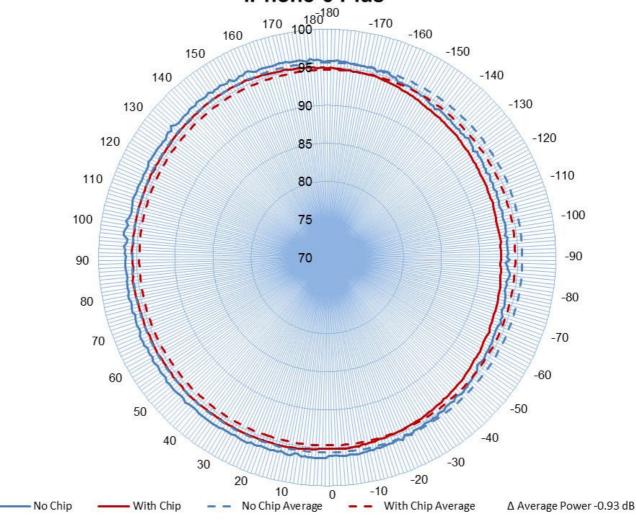
Field Strength Polar Plot iPhone 6



Graph 2 - Apple iPhone 6

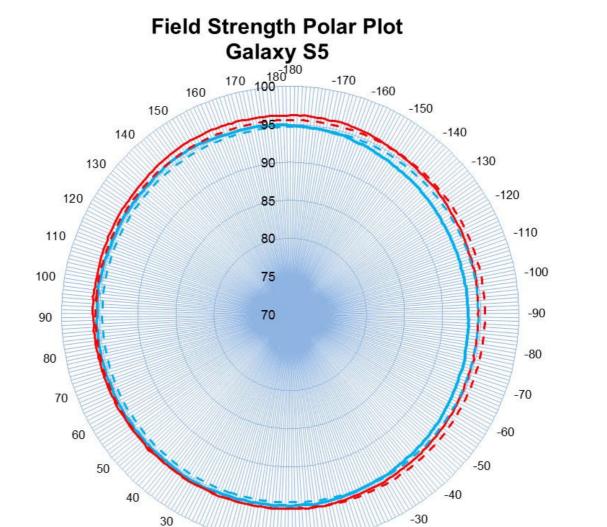
APPENDIX B3 POLAR RADIATION PATTERN MEASUREMENT

Field Strength Polar Plot iPhone 6 Plus



Graph 3 - Apple iPhone 6 Plus

APPENDIX B4 POLAR RADIATION PATTERN MEASUREMENT



Graph 4 – Samsung Galaxy S5

10

No Chip Average

20

With Chip

No Chip

-20

With Chip Average

Δ Average Power 0.87 dB

-10

-60

Δ Average Power -1.28 dB

-50

-40

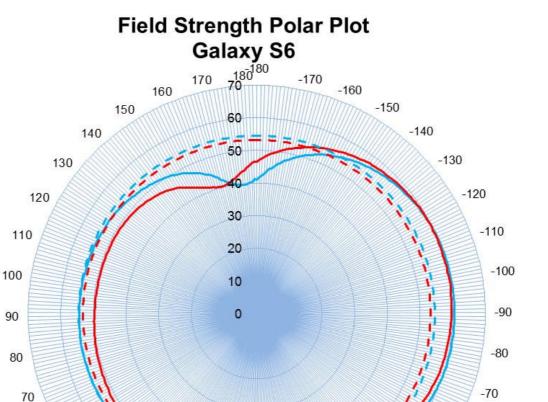
-30

-20

With Chip Average

-10

APPENDIX B5 POLAR RADIATION PATTERN MEASUREMENT



Graph 5 – Samsung Galaxy S6

10

No Chip Average

60

No Chip

50

40

With Chip

30

20